

MBR340

Preferred Device

Axial Lead Rectifier

This device employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlap contact. Ideally suited for use as rectifiers in low-voltage, high-frequency inverters, free wheeling diodes, and polarity protection diodes.

Features

- Extremely Low V_F
- Low Power Loss/High Efficiency
- Highly Stable Oxide Passivated Junction
- Low Stored Charge, Majority Carrier Conduction
- Pb-Free Packages are Available*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.1 Gram (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Cathode indicated by Polarity Band

MAXIMUM RATINGS

| Rating | Symbol | Max | Unit |
|--|---------------------------------|----------------|------------------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V_{RRM} V_{RWM} V_R | 40 | V |
| Average Rectified Forward Current $T_A = 65^\circ\text{C}$ ($R_{\theta JA} = 28^\circ\text{C/W}$, P.C. Board Mounting) | I_O | 3.0 | A |
| Non-Repetitive Peak Surge Current (Note 1) (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz, $T_L = 75^\circ\text{C}$) | I_{FSM} | 80 | A |
| Operating and Storage Junction Temperature Range (Reverse Voltage Applied) (Note 2) | T_J, T_{stg} | -65 to +175 | $^\circ\text{C}$ |

THERMAL CHARACTERISTICS

| Rating | Symbol | Max | Unit |
|--|-----------------|-----|--------------------|
| Thermal Resistance, Junction-to-Ambient (see Note 5, Mounting Method 3) | $R_{\theta JA}$ | 28 | $^\circ\text{C/W}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Lead Temperature reference is cathode lead 1/32 in from case.
2. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

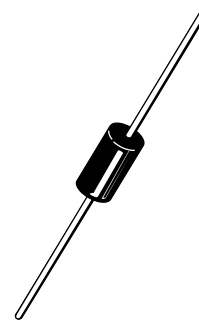
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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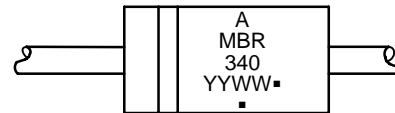
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SCHOTTKY BARRIER RECTIFIER 3.0 AMPERES, 40 VOLTS



AXIAL LEAD
CASE 267-05
(DO-201AD)
STYLE 1

MARKING DIAGRAM



A = Assembly Location
YY = Year
WW = Work Week
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping† |
|-----------|-------------------------|------------------|
| MBR340 | Axial Lead | 500 Units / Bag |
| MBR340G | Axial Lead (Pb-Free) | 500 Units / Bag |
| MBR340RL | Axial Lead | 1500/Tape & Reel |
| MBR340RLG | Axial Lead (Pb-Free) | 1500/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

MBR340

ELECTRICAL CHARACTERISTICS ($T_L = 25^\circ\text{C}$ unless otherwise noted) (Note 3)

| Characteristic | Symbol | Max | Unit |
|--|--------|-------------------------|------|
| Maximum Instantaneous Forward Voltage (Note 4) ($i_F = 1.0$ Amp) ($i_F = 3.0$ Amp) ($i_F = 9.4$ Amp) | V_F | 0.500 0.600 0.850 | V |
| Maximum Instantaneous Reverse Current @ Rated dc Voltage (Note 4) $T_L = 25^\circ\text{C}$ $T_L = 100^\circ\text{C}$ | i_R | 0.60 20 | mA |

3. Lead Temperature reference is cathode lead 1/32in from case.
4. Pulse Test: Pulse Width = 300 μs , Duty Cycle = 2.0%.

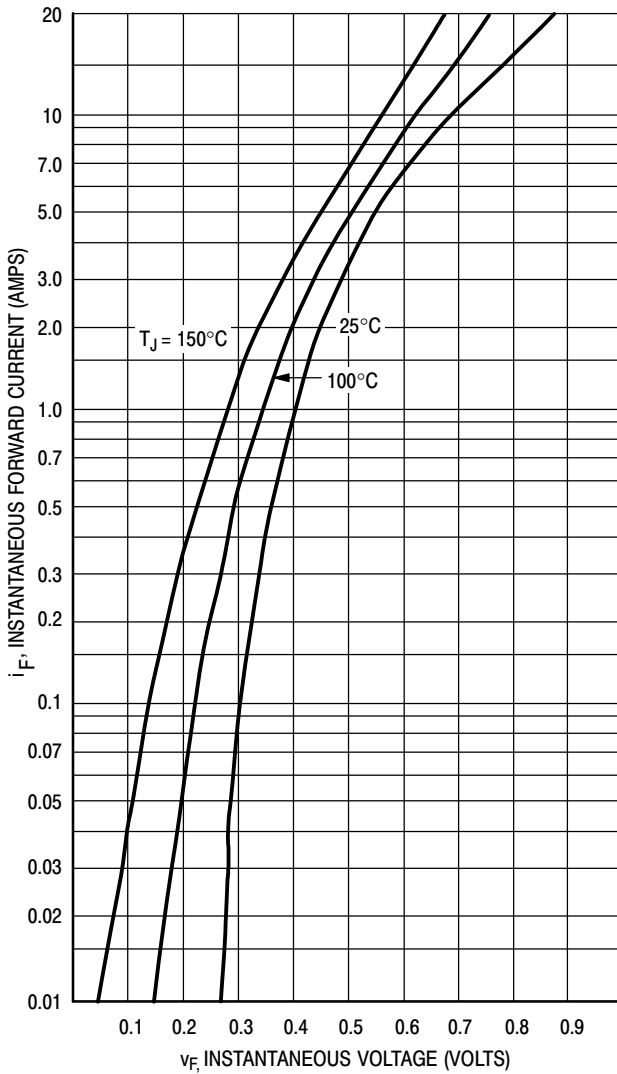


Figure 1. Typical Forward Voltage

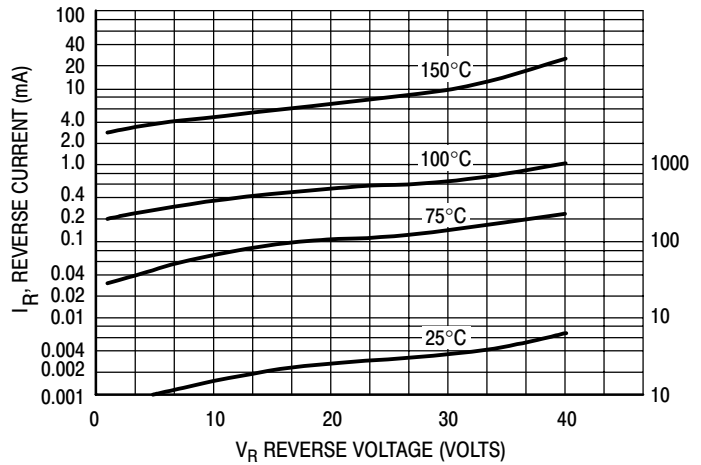


Figure 2. Typical Reverse Current*

*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

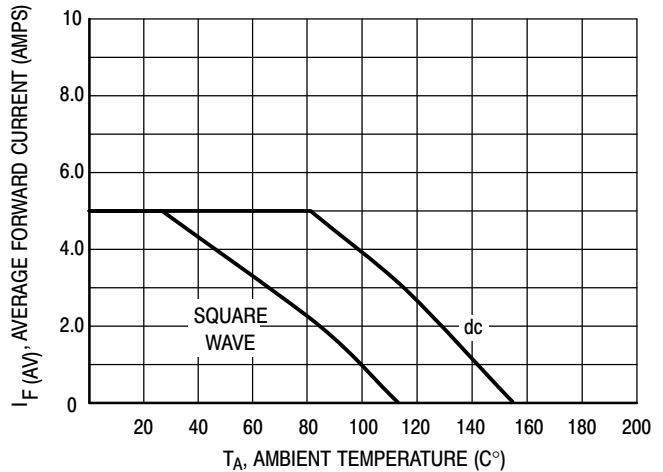


Figure 3. Current Derating
(Mounting Method #3 per Note 5)

MBR340

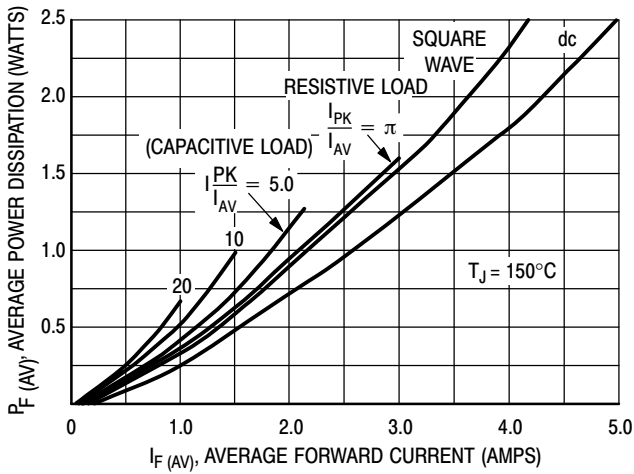


Figure 4. Power Dissipation

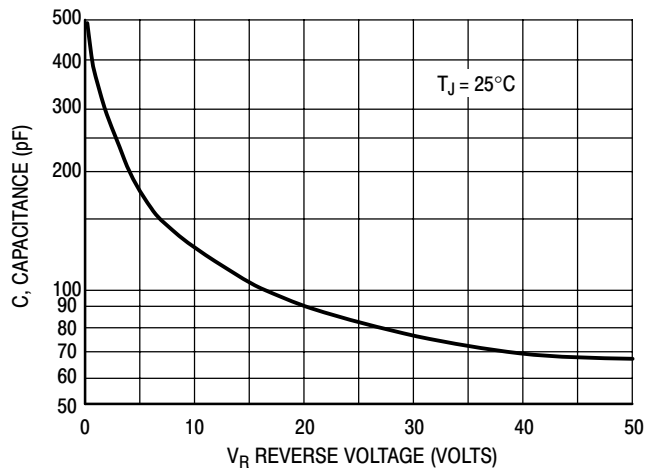


Figure 5. Typical Capacitance

NOTE 5 — MOUNTING DATA

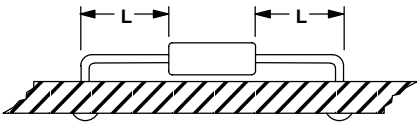
Data shown for thermal resistance junction-to-ambient ($R_{\theta JA}$) for the mountings shown is to be used as typical guideline values for preliminary engineering, or in case the tie point temperature cannot be measured.

TYPICAL VALUES FOR $R_{\theta JA}$ IN STILL AIR

| Mounting Method | Lead Length, L (in) | | | | $R_{\theta JA}$ |
|-----------------|---------------------|-----|-----|-----|-----------------------------|
| | 1/8 | 1/4 | 1/2 | 3/4 | |
| 1 | 50 | 51 | 53 | 55 | $^{\circ}\text{C}/\text{W}$ |
| 2 | 58 | 59 | 61 | 63 | $^{\circ}\text{C}/\text{W}$ |
| 3 | 28 | | | | $^{\circ}\text{C}/\text{W}$ |

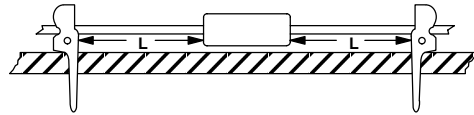
Mounting Method 1

P.C. Board where available copper surface is small.



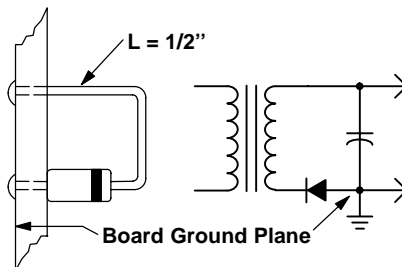
Mounting Method 2

Vector Push-In Terminals T-28



Mounting Method 3

P.C. Board with 2-1/2" X 2-1/2" copper surface.





AXIAL LEAD
CASE 267-05
ISSUE G

DATE 06/06/2000



SCALE 1:1



- NOTES:
1. DIMENSIONS AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 267-04 OBSOLETE, NEW STANDARD 267-05.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|------|
| | MIN | MAX | MIN | MAX |
| A | 0.287 | 0.374 | 7.30 | 9.50 |
| B | 0.189 | 0.209 | 4.80 | 5.30 |
| D | 0.047 | 0.051 | 1.20 | 1.30 |
| K | 1.000 | --- | 25.40 | --- |

STYLE 1:
 PIN 1. CATHODE (POLARITY BAND)
 2. ANODE

STYLE 2:
 NO POLARITY

| | | |
|-------------------------|--------------------|---|
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| DESCRIPTION: | AXIAL LEAD | PAGE 1 OF 1 |

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